

Parameter		Symbol	Тур	Max	Units			
Maximum Junction-to-Ambient <sup>A</sup>	t ≤ 10s	D	31	40	C/W			
Maximum Junction-to-Ambient <sup>A</sup>	Steady State	$R_{ extsf{ heta}JA}$	59	75	C/W			
Maximum Junction-to-Lead <sup>C</sup>	Steady State	$R_{ ext{ heta}JL}$	16	24	°C/W			

Symbol	Parameter	Conditions	Min	Тур	Max	Units				
STATIC PARAMETERS										
$BV_{DSS}$	Drain-Source Breakdown Voltage	$I_{D} = -250 \mu A, V_{GS} = 0 V$	-40			V				
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{DS} = -40V, V_{GS} = 0V$			-1	μA				
		T <sub>J</sub> = 55℃			-5	μ				
I <sub>GSS</sub>	Gate-Body leakage current	$V_{DS} = 0V, V_{GS} = \pm 20V$			±100	nA				
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS} I_D = -250 \mu A$	-1.7	-1.9	-2.5	V				
I <sub>D(ON)</sub>	On state drain current	$V_{GS} = -10V, V_{DS} = -5V$	-120			A				
R <sub>DS(ON)</sub>	Static Drain-Source On-Resistance	$V_{GS} = -10V, I_{D} = -10A$		12.5	15					
		T_=125℃		19	23	mΩ				
		$V_{GS} = -4.5V, I_{D} = -8A$		16	20					
<b>g</b> fs	Forward Transconductance	$V_{DS} = -5V, I_{D} = -10A$		25		S				
$V_{SD}$	Diode Forward Voltage	$I_{S} = -1A, V_{GS} = 0V$		-0.7	-1	V				
I <sub>S</sub>	Maximum Body-Diode Continuous Curr			-3	А					
DYNAMIC	PARAMETERS									
C <sub>iss</sub>	Input Capacitance			2500	3000	pF				
C <sub>oss</sub>	Output Capacitance	$V_{GS}$ =0V, $V_{DS}$ =-20V, f=1MHz		260		pF				
C <sub>rss</sub>	Reverse Transfer Capacitance			180		pF				
R <sub>g</sub>	Gate resistance	V <sub>GS</sub> =0V, V <sub>DS</sub> =0V, f=1MHz	2.5	4	6	Ω				
SWITCHI	NG PARAMETERS									
Q <sub>g</sub> (10V)	Total Gate Charge			42	55	nC				
Q <sub>g</sub> (4.5V)	Total Gate Charge	V <sub>GS</sub> =-10V, V <sub>DS</sub> =-20V, I <sub>D</sub> =-10A		18.6		nC				
Q <sub>gs</sub>	Gate Source Charge	$v_{GS} = 100, v_{DS} = 200, v_{D} = 10A$		7		nC				
Q <sub>gd</sub>	Gate Drain Charge			8.6		nC				
t <sub>D(on)</sub>	Turn-On DelayTime			9.4		ns				
t <sub>r</sub>	Turn-On Rise Time	V <sub>GS</sub> =-10V, V <sub>DS</sub> =-20V,		20		ns				
t <sub>D(off)</sub>	Turn-Off DelayTime	$R_L = 2\Omega, R_{GEN} = 3\Omega$		55		ns				
t <sub>f</sub>	Turn-Off Fall Time	] [		30		ns				
t <sub>rr</sub>	Body Diode Reverse Recovery Time	I <sub>F</sub> =-10A, dI/dt=100A/μs		38	49	ns				
Q <sub>rr</sub>	Body Diode Reverse Recovery Charge	I <sub>F</sub> =-10A, dI/dt=100A/μs		47		nC				

## Electrical Characteristics (T<sub>J</sub>=25°C unless otherwise noted)

A: The value of R<sub>0JA</sub> is measured with the device mounted on  $1in^2$  FR-4 board with 2oz. Copper, in a still air environment with T<sub>A</sub> = 25°C. The value in any given application depends on the user's specific board design.

B: Repetitive rating, pulse width limited by junction temperature.

C. The R  $_{\rm 6JA}$  is the sum of the thermal impedence from junction to lead R  $_{\rm 6JL}$  and lead to ambient.

D. The static characteristics in Figures 1 to 6 are obtained using t  $\leqslant$  300 $\mu s$  pulses, duty cycle 0.5% max.

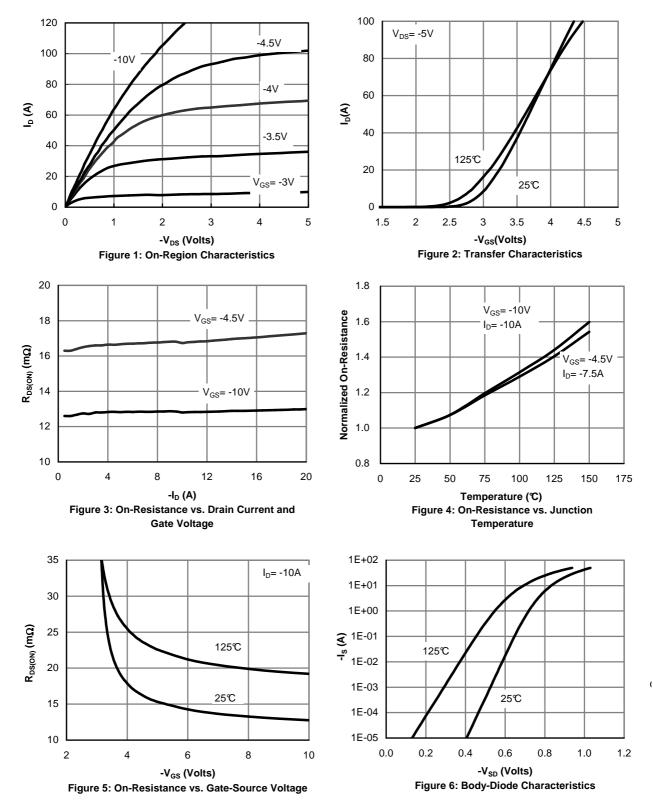
E. These tests are performed with the device mounted on 1 in<sup>2</sup> FR-4 board with 2oz. Copper, in a still air environment with  $T_A=25$ °C. The SOA curve provides a single pulse rating.

F. The current rating is based on the t  $\leqslant$  10s thermal resistance rating.

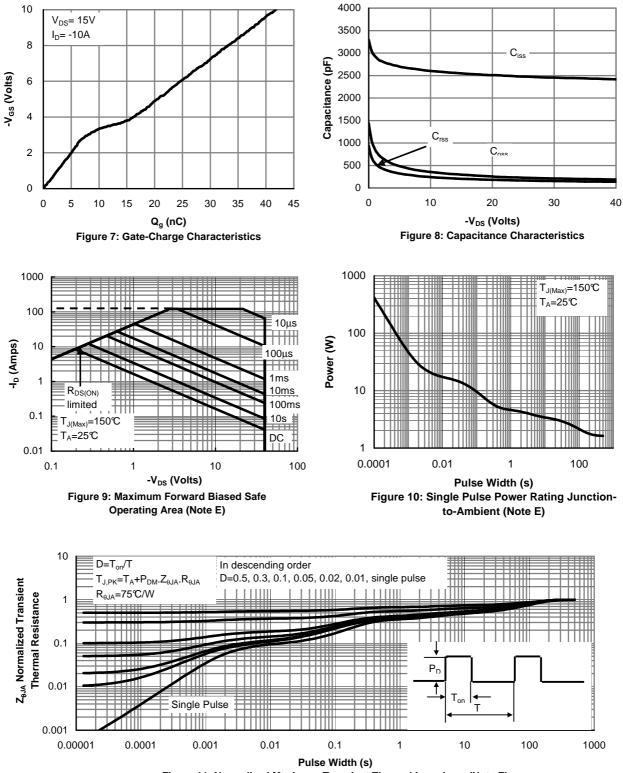
G.  $E_{AR}$  and  $I_{AR}$  ratings are based on low frequency and duty cycles to keep  $T_{j}{=}25C.$ 

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## TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS



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Figure 11: Normalized Maximum Transient Thermal Impedance(Note E)

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